Diode Semiconductor Device - Page 1 of 1



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### **Inclosure Material:**

Metal and glass

### **Overall Length:**

0.250 inches

# **Terminal Length:**

Between 0.115 inches and 0.135 inches

### **Overall Height:**

0.130 inches

**Overall Width:** 

0.060 inches

### **Mounting Method:**

Terminal

### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

800.0 breakdown voltage, dc

# Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius case

### **Special Features:**

O/a dimensions include holder but not leads; junction pattern arrangement: pin; field force effect type: electrostatic charge

# **Precious Material And Location:**

Leads 99.99pct and holder plated gold

### **Precious Material:**

Gold

# **Test Data Document:**

56232-1216947 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# Terminal Type And Quantity:

2 ribbon

Shelf Life:

N/a

#### Unit Of Measure:

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#### **Demilitarization:**

No

#### Fiig:

A110a0